

CMOS Dual 2-Input NAND Buffer/Driver

High-Voltage Type (20-Volt Rating)

The CD40107B is a dual 2-input NAND buffer/driver containing two independent 2-input NAND buffers with open-drain single n-channel transistor outputs. This device features a wired-OR capability and high output sink current capability (136 mA typ. at V_{DD} = 10 V, V_{DS} = 1 V). The CD40107B is supplied in 8-lead hermetic dual-in-line ceramic packages (F3A suffix), 8-lead dual-in-line plastic packages (E suffix), 8-lead small-outline packages (M, M96, MT, and PSR suffixes), and 8-lead thin shrink small-outline packages (PW and PWR suffixes).

Features:

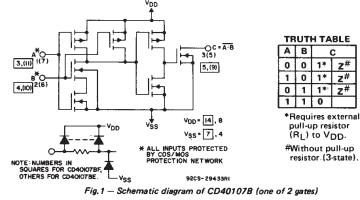
- . 32 times standard B-Series output current drive sinking capability -136 mA typ. @ VDD = 10 V, VDS = 1 V
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 µA at 18 V over full package-temperature range;
- 100 nA at 18 V and 25°C 5-V, 10-V, and 15-V parametric ratings
- Noise margin, full package temperature

range, RL to VDD = 10 kΩ:

1 V at V_{DD} = 5 V

2 V at V_{DD} = 10 V

2.5 V at $V_{DD} \approx 15$ V * Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



- Applications
 - Driving relays, lamps, LEDs
 - Line driver
 - Level shifter (up or down)

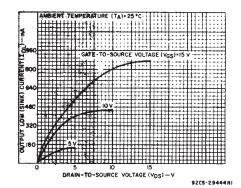
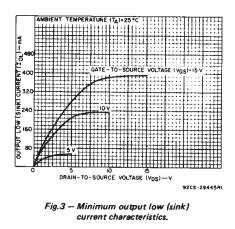


Fig.2 - Typical output low (sink) current characteristics.



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MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V _{DD})
Voltages referenced to V _{SS} Terminal)
INPUT VOLTAGE RANGE, ALL INPUTS
DC INPUT CURRENT, ANY ONE INPUT
POWER DISSIPATION PER PACKAGE (PD):
For $T_A = -55^{\circ}C$ to $+100^{\circ}C$
For $T_A = +100^{\circ}C$ to $+125^{\circ}C$ Derate Linearity at $12mW/^{\circ}C$ to $200mW$
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T _A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
OPERATING-TEMPERATURE RANGE (T _A)55°C to +125°C
STORAGE TEMPERATURE RANGE (Tstg)65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10s max

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LI		
CHARACTERISTIC	MIN.	MAX.	UNITS
Supply-Voltage Range (For TA=			ĺ
Full Package-Temperature Range)	3	18	v

CD40107B Types

F = D · F

92CS-294348

FUNCTIONAL DIAGRAM

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}C$, $C_L = 50 \text{ pF}$, input t_r , $t_f = 20 \text{ ns}$

	TEST CONDIT	TIONS	LIMITS		
CHARACTERISTIC		V _{DD} Volts	Typ.	Max.	UNITS
Propagation Delaw		5	100	200	
Propagation Delay: High-to-Low, tPHL	R _L * = 120 Ω	10	45	90	ns
	_	15	30	60	
Low-to-High, tPLH		5	100	200	
	RL* = 120 Ω	10	60	120	ns
		15	50	100	
Transition Time:		5	50	100	
High-to-Low, tTHL	RL* = 120 Ω	10	20	40	ns
High to Low, CIAL		15	10	20	t a la tr
		5	50	100	
Low-to-High, t _{TLH}	RL* = 120 Ω	10	35	70	ns
		15	25	50]
Average Input Capacitance, CIN	Any Input		5	7.5	pF
Average Output Capacitance, COUT	Any Output		30	-	pF

* RL is external pull-up resistor to VDD.

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)						UNITS		
ISTIC				L				+25				
	(V)	(V)	(V)	-55	-40	+85	+125	Min.	Typ.	Max.		
Quiescent Device		0,5	5	1	1	30	30	-	0.02	1		
Current		0,10	10	2	2	60	60	-	0.02	2		
IDD Max.	_	0,15	15	4	4	120	120	_	0.02	4	μΑ	
-00	-	0,20	20	20	20	600	600		0.04	20		
Output Low	0.4	0,5	5	21	20	14	12	16	32	-		
(Sink) Current	1	0,5	5	44	42	30	25	34	68	-		
IOL Min.	0.5	0,10	10	49	46	32	28	37	74	-	mA	
.OL	1	0,10	10	89	85	60	51	68	136	-		
	0.5	0,15	15	66	63	44	38	50	100	-		
Output High (Source) Current IOH Min.	No Internal Pull-Up Device											
Input Low	4.5	· —	5	1.5 1.5				1.5				
Voltage	9		10			3			·	3		
VIL Max.*	13.5	-	15		4		-	_	4			
Input High Voltage VIH Min.*	0.5,4.5	-	5		3.5			3.5	_	_	l v	
	1,9	_	10		7			7	-	—		
	1.5,13.5	-	15	11 11					-			
Input Current IN Max.		0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μA	
Output Leakage Current IOZ Max.	18	0,18	18	2	2	20	20	—	10 ⁻⁴	2	μA	

* Measured with external pull-up resistor, RL = 10 k Ω to VDD.

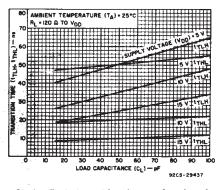
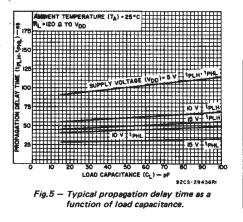


Fig.4 - Typical transition time as a function of load capacitance.



3

COMMERCIAL CMOS HIGH VOLTAGE ICs

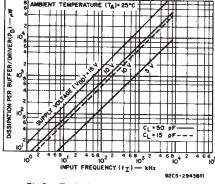


Fig.6 - Typical power dissipation as a function of input frequency.

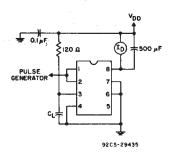
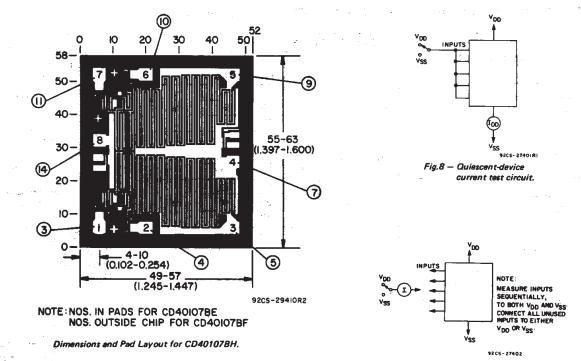
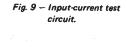
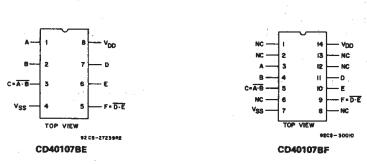


Fig. 7 – Power-dissipation test circuit for CD40107BE.

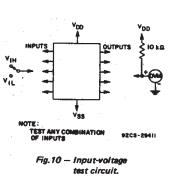


Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch) .





TERMINAL ASSIGNMENTS



Special Considerations for CD40107B

1. Limiting Capacitive Currents for CL > 500 pF, VDD > 15 V. For VDD > 15 V, and load capacitance

For VDD > 15 V, and load capacitance (CL) from output to ground > 500 pF, an external 25 Ω series limiting resistor should be inserted between the output terminal and CL. No external resistor is necessary if CL < 500 pF or VDD < 15 V.

2. Driving Inductive Loads

When using the CD40107B to drive inductive loads, the load should be shunted with a diode to prevent high voltages from developing across the CD40107B output.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD40107BE	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD40107BEE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD40107BF	ACTIVE	CDIP	J	14	1	TBD	Call TI	Level-NC-NC-NC
CD40107BF3A	ACTIVE	CDIP	J	14	1	TBD	Call TI	Level-NC-NC-NC
CD40107BM	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40107BM96	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40107BM96E4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40107BME4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40107BMT	ACTIVE	SOIC	D	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40107BMTE4	ACTIVE	SOIC	D	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40107BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40107BPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40107BPW	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40107BPWE4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40107BPWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40107BPWRE4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is



PACKAGE OPTION ADDENDUM

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J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

MECHANICAL DATA

MPDI001A - JANUARY 1995 - REVISED JUNE 1999



- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001

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D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012 variation AA.



MECHANICAL DATA

PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



MECHANICAL DATA

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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Mailing Address:

Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

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